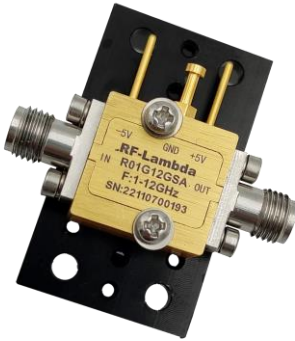


Wide Band Low Noise Amplifier 1GHz-12GHz



Product Description

R01G12GSA is a wide band low noise amplifier with a frequency range of 1 to 12GHz.

The power output of this amplifier is 18dBm typical. The typical gain is 17dB with a flatness of ± 0.8 dB.

The working temperature of this product is between - 40°C and + 85°C.

Features

- Wide Band Low Noise Amplifier
- Gain 17dB Typical
- P1dB Output Power 18dBm Typical
- Output Saturation Power 20dBm Typical
- Supply Voltage +5V, -5V
- 50 Ohm Matched Input/Output
- Low Noise Figure +2.0dB Typical
- Gain Flatness +/-0.8dB

Typical Applications

- Wireless Infrastructure
- Military and Aerospace Applications
- Test Instrumentation
- Radar Systems
- 5G Wireless Communications
- Microwave Radio Systems
- TR Modules
- Research and Development
- Cellular Base Stations

Electrical Specifications (T_A=+25°C)

Parameter	Min	Typ	Max	Min	Typ	Max	Units
Frequency Range	1		6	6		12	GHz
Gain	15	17		14	16		dB
Gain Flatness		± 0.8			± 0.8		dB
Gain Variation Over Temperature (-40°C~+85°C)		± 0.6			± 0.6		dB
Noise Figure		1.6	2.2		2.0	2.5	dB
Input VSWR		1.5			1.6		: 1
Output VSWR		1.4			1.4		: 1
Output 1dB Compression Point (P1dB)	15	18		12	16		dBm
Saturated Output Power (Psat)		20			17		dBm
Output Third Order Intercept (OIP3)		30			28		dBm
Isolation S12		-25			-27		dB
Supply Current (Vcc=+5V)		70	85		70	85	mA
Weight	Net		0.024Max.				lbs.
	Including Heat Sink		0.055Max.				
Impedance			50				Ohms
Input / Output Connectors			SMA-Female (Input) – SMA-Female (Output)				
Package			Epoxy Sealed (Standard)				
			Hermetically Sealed (Optional)				

Absolute Maximum Ratings

Parameter	Rating
Operating Voltage	+5.5V, -5.5V
*RF Input Power (RFIN)	+12dBm

Bias Up Procedure

- 1.Connect Ground Pin
- 2.Connect input and output
- 3.Connect -5V biasing
- 4.Connect +5V biasing

Bias Down Procedure

- 1.Turn off +5V biasing
- 2.Turn off -5V biasing
- 3.Remove RF connection
- 4.Remove Ground.

Environmental Specifications and Test Standards

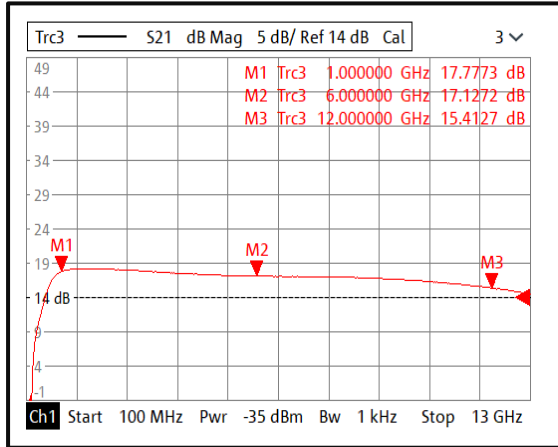
Parameter	Description
Operational Temperature	-40°C to +85°C (Case Temperature)
Storage Temperature	-50°C to +105°C
Thermal Shock	-40°C → +85°C (5 Cycles / 10 hours)
**Random Vibration	MIL-STD-202G Table 214-I, Test Condition Letter C 1.5 Hours Per Axis
High Temperature Burn In	Temperature +85°C for 72 Hours
Shock	1. Weight >20g, 50g half sine wave for 11ms, Speed variation 3.44m/s 2. Weight <=20g, 100g Half sine wave for 6ms, Speed variation 3.75m/s 3. Total 18 times (6 directions, 3 repetitions per direction).
Altitude	Standard: 30,000 Ft (Epoxy Sealed Controlled Environment) Optional: Hermetically Sealed (60,000 ft. 1.0 PSI min)
Hermetically Sealed (Optional)	MIL-STD-883 (For Hermetically Sealed Units)

*Maximum RF input power is set to assure safety of amplifier. Input power may be increased at own risk to achieve full power of amplifier. Please reference gain and power curves.

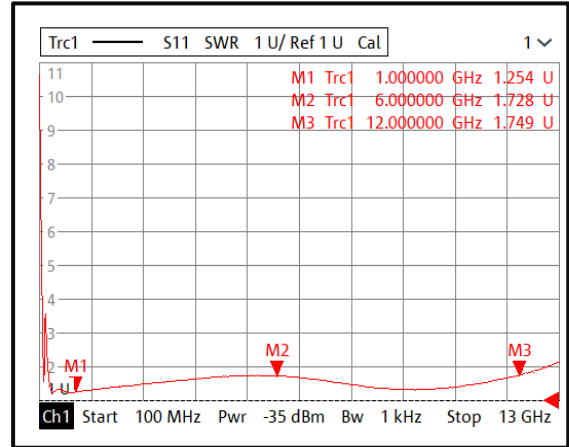
**For vibration testing details please see additional information section.

Typical Performance Plots

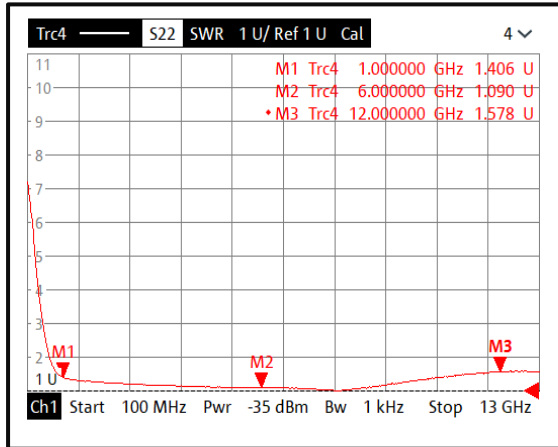
Gain@+25°C



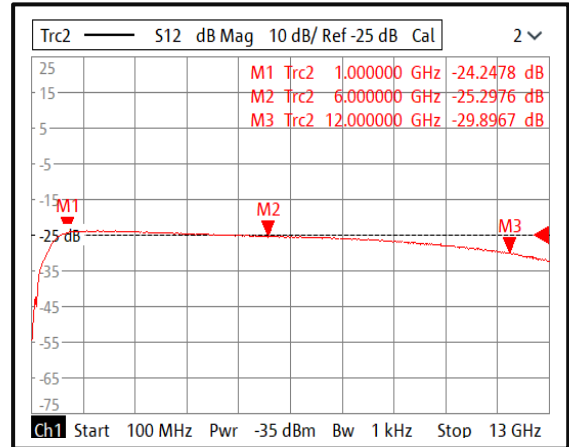
Input VSWR@+25°C



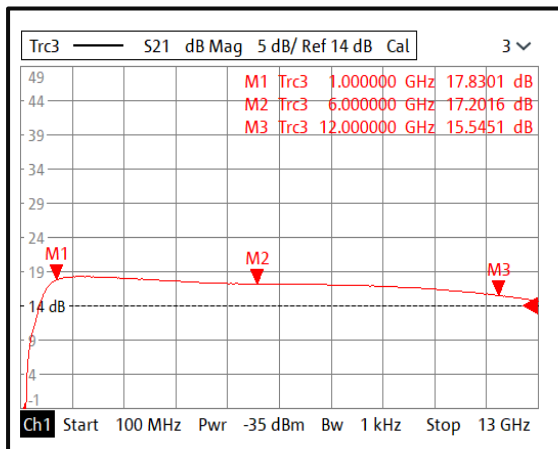
Output VSWR@+25°C



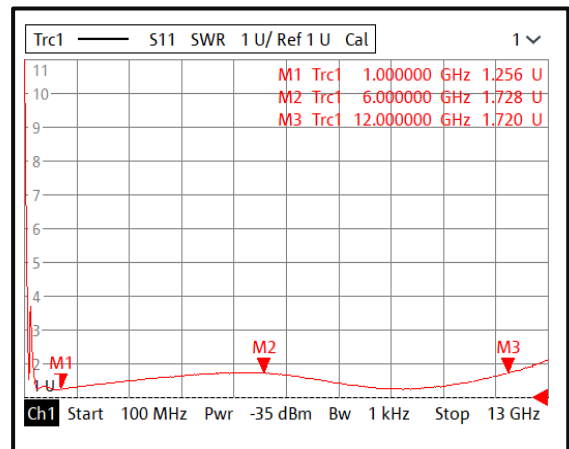
Isolation@+25°C



Gain@-40°C

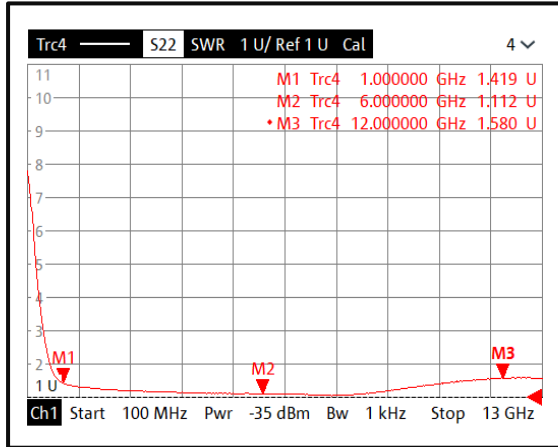


Input VSWR@-40°C

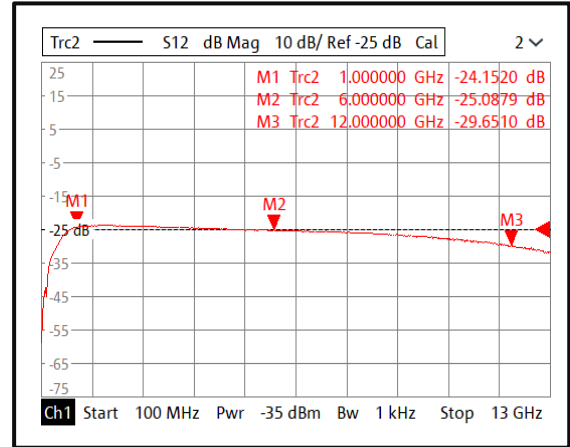


Typical Performance Plots

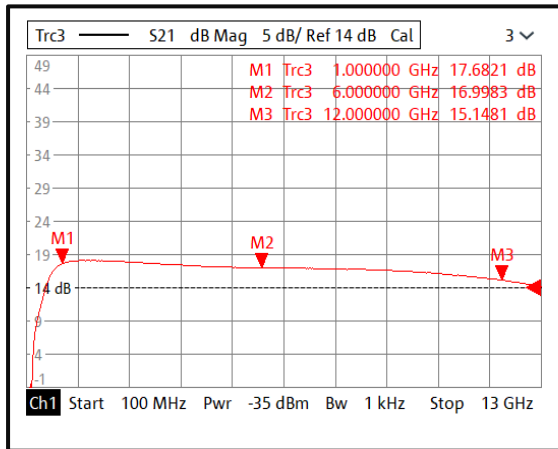
Output VSWR @-40°C



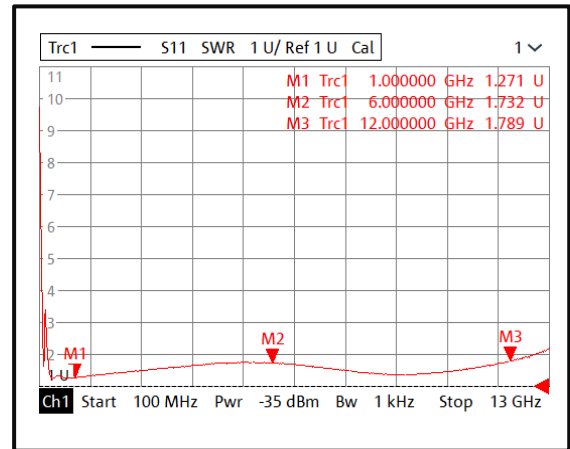
Isolation @-40°C



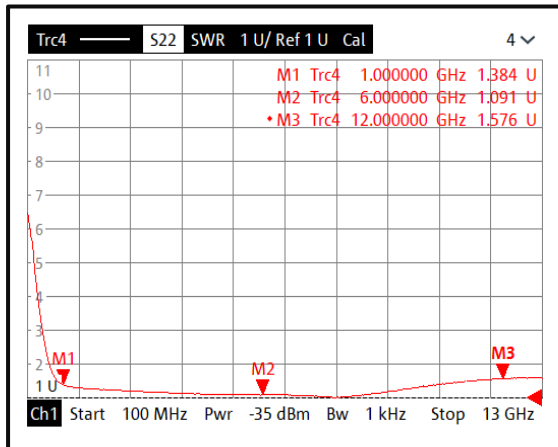
Gain @+85°C



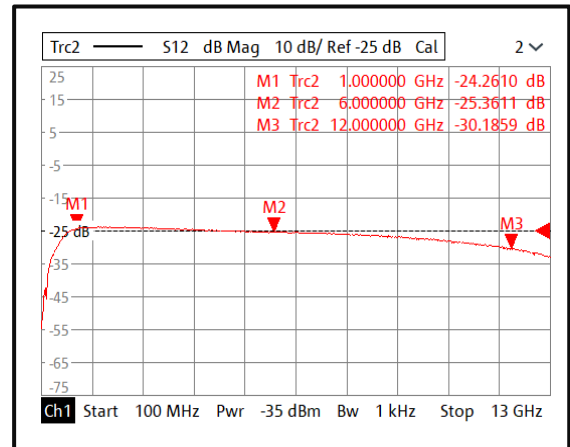
Input VSWR @+85°C



Output VSWR @+85°C

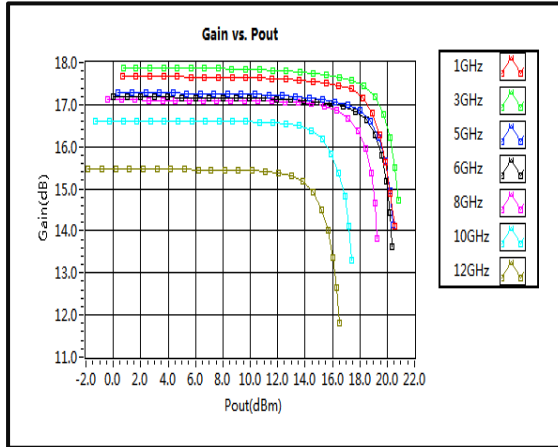


Isolation @+85°C

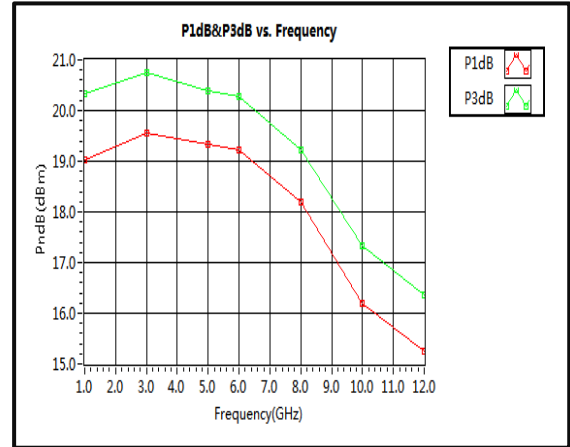


Typical Performance Plots

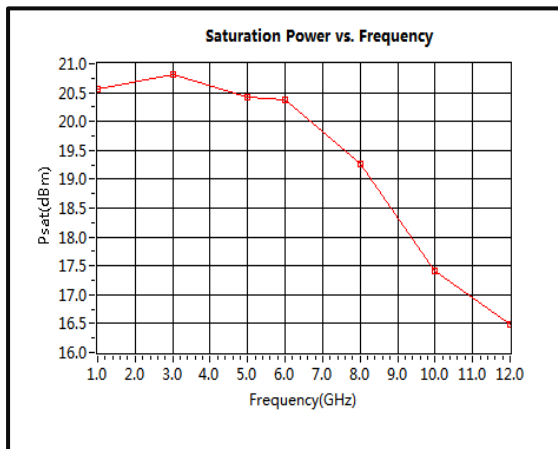
Gain vs. Output Power



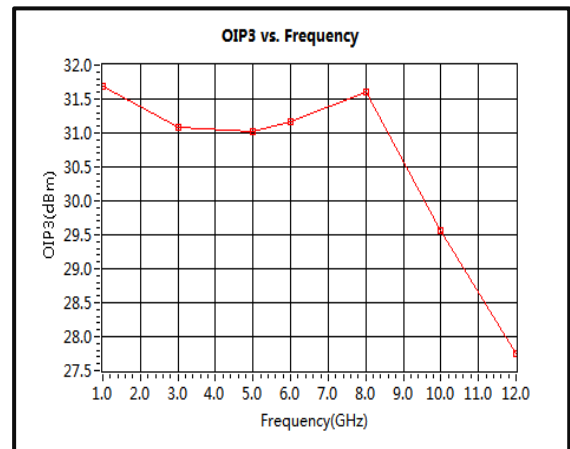
P1dB & P3dB vs. Frequency



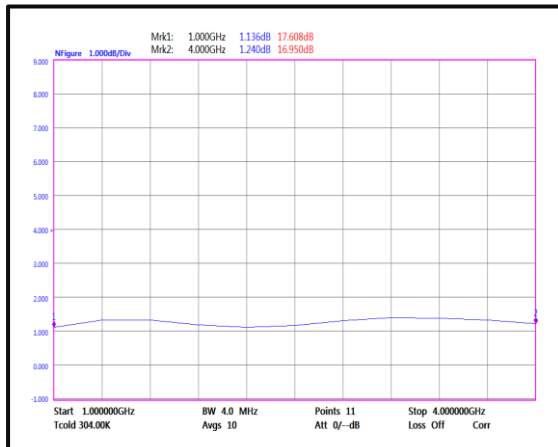
Saturation Power vs. Frequency



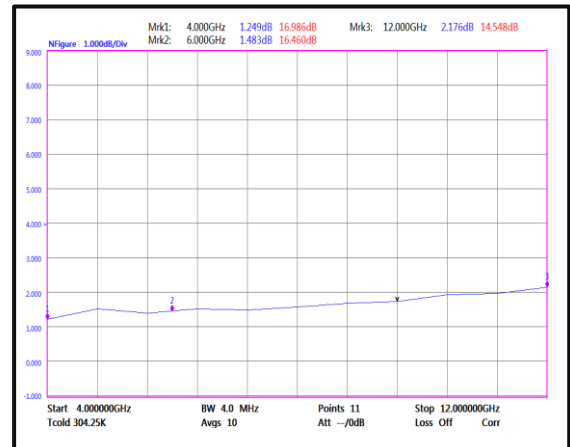
Output Third Order Intercept (OIP3)



Noise Figure(1GHz-4GHz)

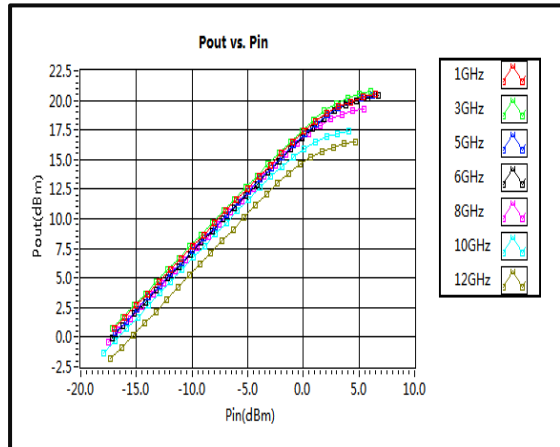


Noise Figure(4GHz-12GHz)

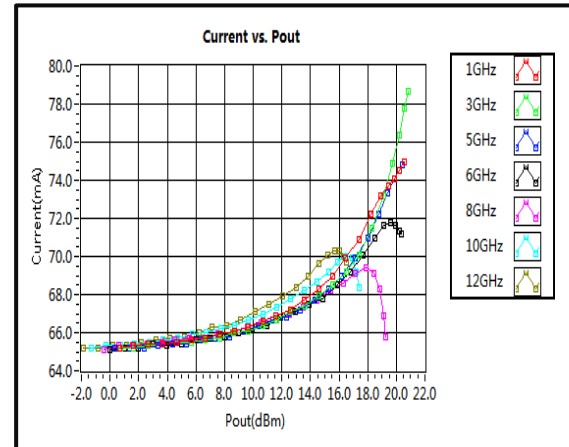


Typical Performance Plots

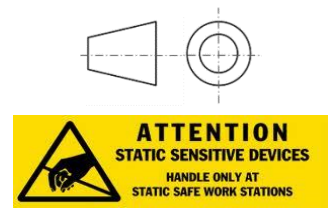
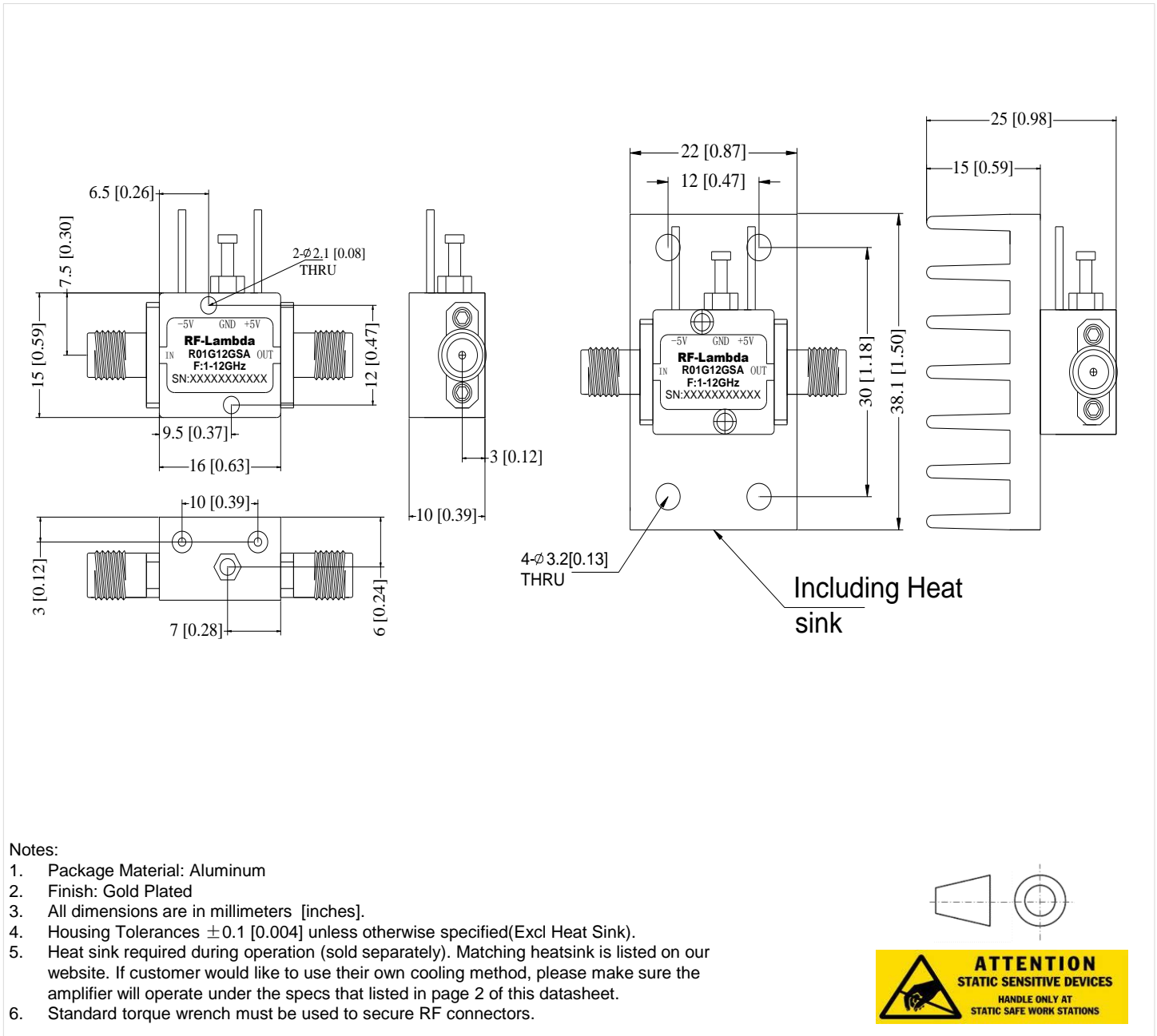
Pout vs. Pin



Current vs. Pout



Outline Drawing



Additional Information

Documentation	Webpage
ESD Policy	https://rflambda.com/pdf/rflambda_esd_control.pdf
Heatsink Lookup Specifications	https://rflambda.com/search_heatsink.jsp
Connector Torque Specifications	https://www.rflambda.com/pdf/Torque_Specifications.pdf
Random Vibration Test Standard	https://www.rflambda.com/pdf/rflambda_random_vibration_MIL-STD-202G.pdf

Ordering Information

Part Number	Modification	Description
R01G12GSA	Standard	1GHz-12GHz Low Noise Amplifier

Amplifier Use

Ensure that the amplifier input and output ports are safely terminated into a proper 50 ohm load before turning on the power. Never operate the amplifier without a load. A proper 50 ohm load is defined as a load with impedance less than 1.9:1 or return loss larger than 10dB relative to 50 Ohm within the specified operating band width.

Power Supply Requirements

Power supply must be able to provide adequate current for the amplifier. Power supply should be able to provide 1.5 times the typical current or 1.2 times the maximum current (whichever is greater).

In most cases, RF - Lambda amplifiers will withstand severe mismatches without damage. However, operation with poor loads is discouraged. If prolonged operation with poor or unknown loads is expected, an external device such as an isolator or circulator should be used to protect the amplifier.

Ensure that the power is off when connecting or disconnecting the input or output of the amp.

Prevent overdriving the amplifier. Do not exceed the recommended input power level.

Adequate heat-sinking required for RF amplifier modules. Please inquire.

Amplifiers do not contain Thermal protection, Reverse DC polarity or Over voltage protection with the exception of a few models. Please inquire.

Proper electrostatic discharge (ESD) precautions are recommended to avoid performance degradation or loss of functionality.

What is not covered with warranty?

Each RF - Lambda amplifier will go through power and temperature stress testing. Since the die, ICs or MMICs are fragile, these are not covered by warranty. Any damage to these will NOT be free to repair.

Important Notice

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